

March 2011

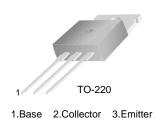
BDX53/A/B/C NPN Epitaxial Silicon Transistor

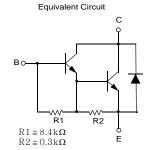
Applications

- Hammer Drivers, Audio Amplifiers Applications
- Power Liner and Switching Applications

Features

- · Power Darlington TR
- Complement to BDX54, BDX54A, BDX54B and BDX54C respectively





Absolute Maximum Ratings $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage : BDX53	45	V	
	: BDX53A	60	V	
	: BDX53B	80	V	
	: BDX53C	100	V	
V_{CEO}	Collector-Emitter Voltage : BDX53	45	V	
	: BDX53A	60	V	
	: BDX53B	80	V	
	: BDX53C	100	V	
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current (DC)	8	Α	
I _{CP}	*Collector Current (Pulse)	12	Α	
I _B	Base Current	0.2	А	
P _C	Collector Dissipation (T _C = 25°C)	60	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 65 to 150	°C	

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Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage : BDX53 : BDX53A : BDX53B : BDX53C	I _C = 100mA, I _B = 0	45 60 80 100			< < < < < < < < < < < < < < < < < < <
I _{CBO}	Collector Cut-off Current : BDX53 : BDX53A : BDX53B : BDX53C	$\begin{aligned} & V_{\text{CB}} = 45\text{V}, \ I_{\text{E}} = 0 \\ & V_{\text{CB}} = 60\text{V}, \ I_{\text{E}} = 0 \\ & V_{\text{CB}} = 80\text{V}, \ I_{\text{E}} = 0 \\ & V_{\text{CB}} = 100\text{V}, \ I_{\text{E}} = 0 \end{aligned}$			200 200 200 200	μΑ μΑ μΑ μΑ
I _{CEO}	Collector Cut-off Current : BDX53 : BDX53A : BDX53B : BDX53C	$\begin{aligned} & V_{CE} = 22V, I_{B} = 0 \\ & V_{CE} = 30V, I_{B} = 0 \\ & V_{CE} = 40V, I_{B} = 0 \\ & V_{CE} = 50V, I_{B} = 0 \end{aligned}$			500 500 500 500	μΑ μΑ μΑ μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			2	mA
h _{FE}	* DC Current Gain	$V_{CE} = 3V, I_{C} = 3A$	750			
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 12mA$			2	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	$I_C = 3A, I_B = 12mA$			2.5	V
V _F	* Parallel Diode Forward Voltage	I _F = 3A I _F = 8A		1.8 2.5	2.5	V V

^{*} Pulse Test: PW=300μs, duty Cycle =1.5% Pulsed

Typical Performance Characteristics

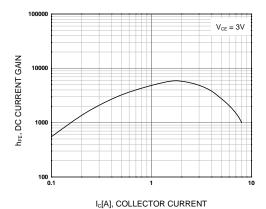


Figure 1. DC current Gain

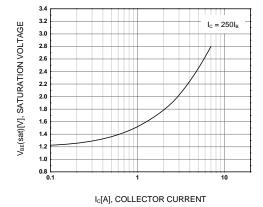


Figure 2. Base-Emitter Saturation Voltage

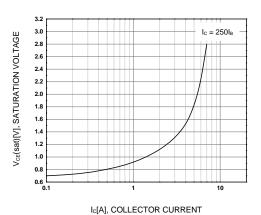


Figure 3. Collector-Emitter Saturation Voltage

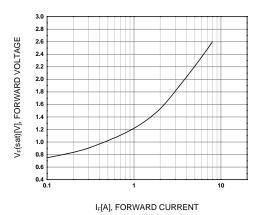


Figure 4. Damper Diode Forward Voltage

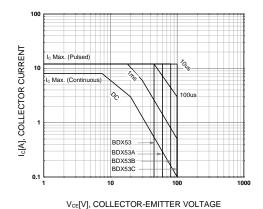


Figure 5. Safe Operating Area

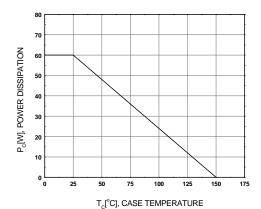
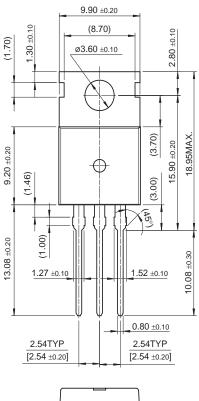
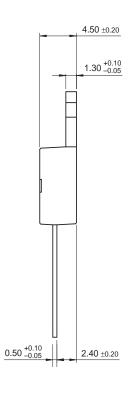


Figure 6. Power Derating

Physical Dimensions

TO-220





10.00 ±0.20

Dimensions in Millimeters



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